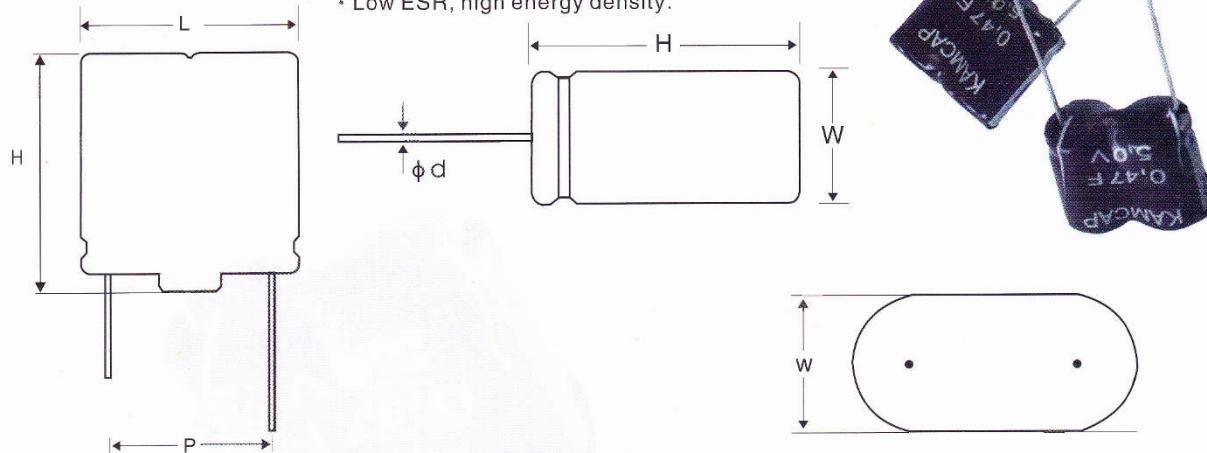


SE Z

FEATURES

- I Serial structure, two cell with the same Characteristics
- IIdeal for backing up of CMOS's, microcomputers, RAM's and the like used in VCR's, turners, TV sets, telephone sets and other.
- Low ESR, high energy density.



SPECIFICATIONS

Operating temperature	-25~+70°C
Rate voltage	5.0V, 5.5V
Surge Voltage	6.3V
Max Capacitance tolerance	-20%~80%
Temperature Characteristics	+70°C ΔC/C ≤30%, ESR≤100% of the specified value at 25°C -25°C ΔC/C ≤50%, ESR≤400% of the specified value at 25°C
High temperature load	After 1000h, +70°C ±2, nominal voltage, ΔC/C ≤30% of the initial measured value, ESR≤400% of the initial specified value
High temperature without load	After 1000h, +70°C ±2, nominal voltage, ΔC/C ≤30% of the initial measured value, ESR≤400% of the initial specified value
Humidity Resistance	After +40°C ±2, 90~95%RH, 240h, ΔC/C ≤30% of the initial measured value, IL≤200% of the initial specified value, ESR≤4 time of the initial specified value

Part Number	Rated Capacitance	Operating Voltage	ESR 1kHz (mΩ)	Size (H×L×W, mm) ±0.5mm	P(mm) ±0.5mm	Φd (mm) ± 0.05mm
SE-5R0-Z334VY	0.33F	5.0V	1600	14×16×8	11.5	0.6
SE-5R0-Z474VY	0.47F	5.0V	1200	14×16×8	11.5	0.6
SE-5R5-Z105VY	1.0F	5.5V	600	22×20×10	14.5	0.6
SE-5R5-Z205VY	2.0F	5.5V	300	25×23×13	17.5	0.6
SE-5R5-Z405VY	4.0F	5.5V	200	25×23×13	17.5	0.6

Characteristic curve

